June 1994

## Monolithic CMOS Analog Switches

## Features

- **This Circuit is Processed in Accordance to MIL-STD-883 and is Fully Conformant Under the Provisions of Paragraph 1.2.1.**
- **ON-Resistance <35$\Omega$**
- **Low Power Consumption (P$_D$ <35$\mu$W)**
- **Fast Switching Action**
  - **t$_{ON}$ <150ns**
  - **t$_{OFF}$ <100ns**
- **Low Charge Injection**
- **DG401/883 Dual SPST; Replaces HI-5041/883**
- **DG403/883 Dual SPDT; Replaces DG190/883B, IH5043/883B, IH5151/883B, HI-5051/883, HI-5043/883B**
- **DG405/883 Dual DPST; Replaces DG184/883B, HI-5045/883, IH5145/883B**
- **TTL, CMOS Compatible**
- **Single or Split Supply Operation**

## Applications

- **Audio Switching**
- **Battery Operated Systems**
- **Data Acquisition**
- **Hi-Rel Systems**
- **Sample and Hold Circuits**
- **Communication Systems**

## Description

The DG401/883, DG403/883 and DG405/883 monolithic CMOS analog switches have TTL and CMOS compatible digital inputs.

These switches feature low analog ON resistance (<35$\Omega$) and fast switch time (t$_{ON}$ <150ns). Low charge injection simplifies sample and hold applications.
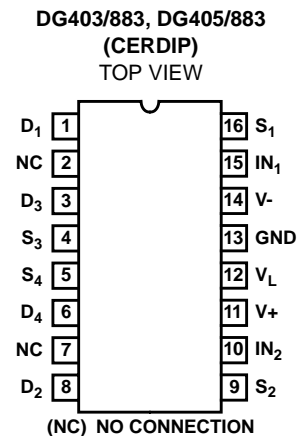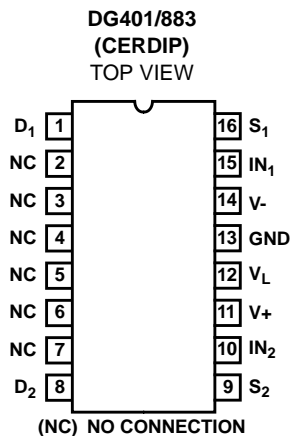
The improvements in the DG401/403/405/883 series are made possible by using a high voltage silicon-gate process. An epitaxial layer prevents the latch-up associated with older CMOS technologies. The 44V maximum voltage range permits controlling 30V peak-to-peak signals. Power supplies may be single-ended from +5V to +34V, or split from ±5V to ±17V.

The analog switches are bilateral, equally matched for AC or bidirectional signals. The ON resistance variation with analog signals is quite low over a ±15V analog input range. The three different devices provide the equivalent of two SPST (DG401/883), two SPDT (DG403/883) or two DPST (DG405/883) relay switch contacts with CMOS or TTL level activation. The pinout is similar, permitting a standard layout to be used, choosing the switch function as needed.
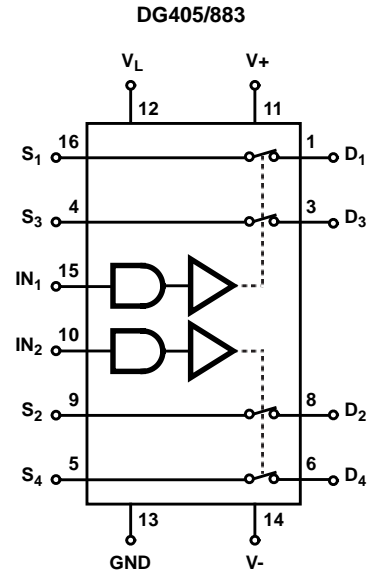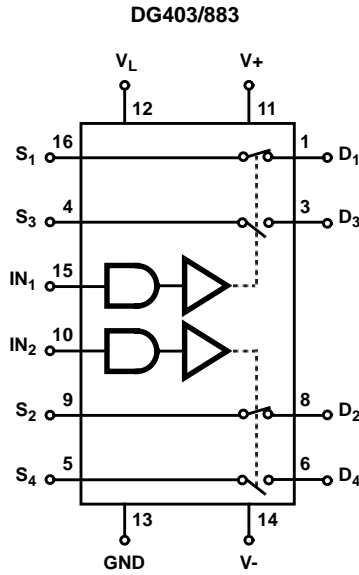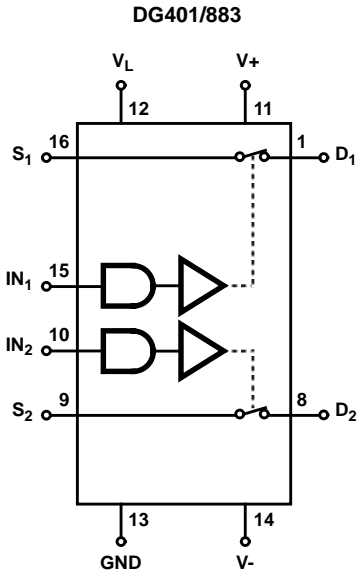
## Ordering Information

| PART NUMBER | TEMPERATURE RANGE | PACKAGE |
|---|---|---|
| DG401AK/883 | -55$^o$C to +125$^o$C | 16 Lead CERDIP |
| DG403AK/883 | -55$^o$C to +125$^o$C | 16 Lead CERDIP |
| DG405AK/883 | -55$^o$C to +125$^o$C | 16 Lead CERDIP |

## Pinouts

**DG401/883**
**(CERDIP)**
TOP VIEW

| | | | |
|---|---|---|---|
| D$_1$ | 1 | 16 | S$_1$ |
| NC | 2 | 15 | IN$_1$ |
| NC | 3 | 14 | V- |
| NC | 4 | 13 | GND |
| NC | 5 | 12 | V$_L$ |
| NC | 6 | 11 | V+ |
| NC | 7 | 10 | IN$_2$ |
| D$_2$ | 8 | 9 | S$_2$ |

**(NC) NO CONNECTION**

**DG403/883, DG405/883**
**(CERDIP)**
TOP VIEW

| | | | |
|---|---|---|---|
| D$_1$ | 1 | 16 | S$_1$ |
| NC | 2 | 15 | IN$_1$ |
| D$_3$ | 3 | 14 | V- |
| S$_3$ | 4 | 13 | GND |
| S$_4$ | 5 | 12 | V$_L$ |
| D$_4$ | 6 | 11 | V+ |
| NC | 7 | 10 | IN$_2$ |
| D$_2$ | 8 | 9 | S$_2$ |

**(NC) NO CONNECTION**

Spec Number **512046**

File Number **3703**

## *Functional Diagrams*

**DG401/883**



**DG403/883**



**DG405/883**



## *Schematic Diagram*
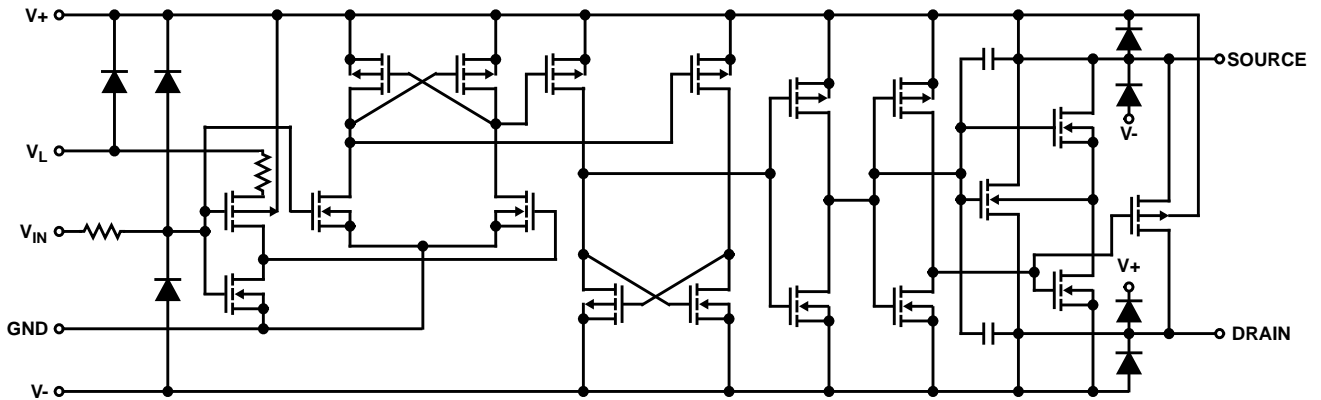


## *Truth Table*

| LOGIC | DG401/883 | DG403/883 | | DG405/883 |
|---|---|---|---|---|
| | SWITCH | SWITCH 1, 2 | SWITCH 3, 4 | SWITCH |
| 0 | OFF | OFF | ON | OFF |
| 1 | ON | ON | OFF | ON |

NOTE: Logic "0" ≤0.8V. Logic "1" ≥2.4V.

## Absolute Maximum Ratings

V+ to V-. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . .+44.0V
GND to V-. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 25V
$V_L$ . . . . . . . . . . . . . . . . . . . . . . . . . . . . . (GND - 0.3V) to (VC+) +0.3V
Digital Inputs (Note 1), $V_S$, $V_D$ . . . . . (V-) -2V to (V+) + 2V or 30mA,
Whichever Occurs First
Continuous (Any Terminal) Current, (Note 1) . . . . . . . . . . . . . .±30mA
Peak Current, S or D (Note 1) . . . . . . . . . . . . . . . . . . . . . . . . .±100mA
   (Pulsed 1ms, 10% Duty Cycle)
Storage Temperature Range (A Suffix) . . . . . . . . . -65$^o$C to +125$^o$C
Lead Temperature (Soldering 10s). . . . . . . . . . . . . . . . . . . +300$^o$C

## Reliability Information

Thermal Resistance (Max)                         $\theta_{JC}$         $\theta_{JA}$
   CERDIP Package . . . . . . . . . . . . . . . . . .  18$^o$C/W   75$^o$C/W
Operating Temperature (A Suffix) . . . . . . . . . . . . . .-55$^o$C to +125$^o$C
Junction Temperature (CerDIP) . . . . . . . . . . . . . . . . . . . . . . . +175$^o$C

CAUTION: *Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.*

## Operating Conditions

Operating Voltage Range . . . . . . . . . . . . . . . . . . . . . . . . . . . . .±20V Max
Operating Temperature Range. . . . . . . . . . . . . . . . -55$^o$C to +125$^o$C
Input Low Voltage. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 0.8V Max

Input High Voltage. . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 2.4V Min
Input Rise and Fall Time . . . . . . . . . . . . . . . . . . . . . . . . . . . . . . 20ns

**TABLE 1.  DC ELECTRICAL PERFORMANCE CHARACTERISTICS**

Device Tested at  V+ = +15V, V- = -15V, $V_L$ = 5V, Unless Otherwise Specified

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUP | TEMPERATURE | LIMITS MIN | LIMITS MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Drain-to-Source ON Resistance | $R_{DS(ON)}$ | V+ = +13.5V, V- = -13.5V, $I_S$ = -10mA, $V_D$ = ±10V | 1 | +25$^o$C | - | 35 | Ω |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | 45 | Ω |
| Delta Drain-to-Source ON Resistance | Delta $R_{DS(ON)}$ | V+ = +16.5V, V- = -16.5V, $I_S$ = -10mA, $V_D$ = +5V, 0V, -5V | 1 | +25$^o$C | - | 3 | Ω |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | 5 | Ω |
| Source OFF Leakage Current | $I_{S(OFF)}$ | V+ = +16.5V, V- = -16.5V, $V_S$ = -15.5V, $V_D$ = +15.5V | 1 | +25$^o$C | - | ±0.25 | nA |
| | | | 2 | +125$^o$C | - | ±20 | nA |
| | | V+ = +16.5V, V- = -16.5V, $V_S$ = +15.5V, $V_D$ = -15.5V | 1 | +25$^o$C | - | ±0.25 | nA |
| | | | 2 | +125$^o$C | - | ±20 | nA |
| Drain OFF Leakage Current | $I_{D(OFF)}$ | V+ = +16.5V, V- = -16.5V, $V_S$ = -15.5V, $V_D$ = +15.5V | 1 | +25$^o$C | - | ±0.25 | nA |
| | | | 2 | +125$^o$C | - | ±20 | nA |
| | | V+ = +16.5V, V- = -16.5V, $V_S$ = +15.5V, $V_D$ = -15.5V | 1 | +25$^o$C | - | ±0.25 | nA |
| | | | 2 | +125$^o$C | - | ±20 | nA |
| Channel ON Leakage Current | $I_{D(ON)}$ + $I_{S(ON)}$ | V+ = +16.5V, V- = -16.5V, $V_S$ = $V_D$ = ±15.5V | 1 | +25$^o$C | - | ±0.4 | nA |
| | | | 2 | +125$^o$C | - | ±40 | nA |
| Low Level Input Current | $I_{IL}$ | $V_{IN}$ Under Test = 0.8V, All Others = 2.4V | 1, 2 | +25$^o$C, +125$^o$C | - | ±1.0 | µA |
| High Level Input Current | $I_{IH}$ | $V_{IN}$ Under Test = 2.4V, All Others = 0.8V | 1, 2 | +25$^o$C, +125$^o$C | - | ±1.0 | µA |
| Positive Supply Current | I+ | V+ = 16.5V, V- = -16.5V, $V_{IN}$ = 0V or 5.0V | 1 | +25$^o$C | - | +1.0 | µA |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | +5.0 | µA |
| Negative Supply Current | I- | V+ = +16.5V, V- = -16.5V, $V_{IN}$ = 0V or 5.0V | 1 | +25$^o$C | - | -1.0 | µA |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | -5.0 | |
| Logic Supply Current | $I_L$ | V+ = +16.5V, V- = -16.5V, $V_{IN}$ 0V or 5V | 1 | +25$^o$C | - | +1.0 | µA |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | +5.0 | |
| Ground Current | $I_{GND}$ | V+ = +16.5V, V- = -16.5V, $V_{IN}$ 0V or 5V | 1 | +25$^o$C | - | -1.0 | µA |
| | | | 2, 3 | +125$^o$C, -55$^o$C | - | -5.0 | |

Spec Number  **512046**

### TABLE 2. AC ELECTRICAL PERFORMANCE CHARACTERISTICS

Device Tested at V+ = +15V, V- = -15V, $V_L$ = 5V, Unless Otherwise Specified

| PARAMETERS | SYMBOL | CONDITIONS | GROUP A SUBGROUP | TEMPERATURE | LIMITS MIN | LIMITS MAX | UNITS |
|---|---|---|---|---|---|---|---|
| Turn On Time | $t_{ON}$ | $R_L$ = 300Ω, $C_L$ = 35pF | 9 | +25°C | - | 150 | ns |
| | | | 10, 11 | +125°C, -55°C | - | 275 | ns |
| Turn Off Time | $t_{OFF}$ | $R_L$ = 300Ω, $C_L$ = 35pF | 9 | +25°C | - | 100 | ns |
| | | | 10 | +125°C | - | 250 | ns |
| | | | 11 | -55°C | - | 175 | ns |
| Break-Before-Make Time Delay (DG403 Only) | $t_D$ | $R_L$ = 300Ω, $C_L$ = 35pF | 9 | +25°C | 10 | 150 | ns |

NOTE:

1. Signals on $S_X$, $D_X$, or $IN_X$ exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

### TABLE 3. ELECTRICAL PERFORMANCE CHARACTERISTICS

Table 3 Intentionally Left Blank.

### TABLE 4. ELECTRICAL TEST REQUIREMENTS

| MIL-STD-883 TEST REQUIREMENTS | SUBGROUPS (SEE TABLES 1 AND 2) |
|---|---|
| Interim Electrical Parameters (Pre Burn-In) | 1 |
| Final Electrical Test Parameters | 1 (Note 1), 2, 3, 9, 10, 11 |
| Group A Test Requirements | 1, 2, 3, 9, 10, 11 |
| Groups C and D Endpoints | 1 |

NOTE:

1. PDA applies to Subgroup 1 only.

## *Die Characteristics*

**DIE DIMENSIONS:**
  2150μm x 1720μm x 485 ± 25μm

**METALLIZATION:**
  Type: Si - Al
  Thickness: 12kÅ ± 1kÅ

**GLASSIVATION:**
  Type: Nitride
  Thickness: 8kÅ ± 1kÅ

**WORST CASE CURRENT DENSITY:**
  $1.5 \times 10^5 A/cm^2$

## *Metallization Mask Layout*

**DG401/883**
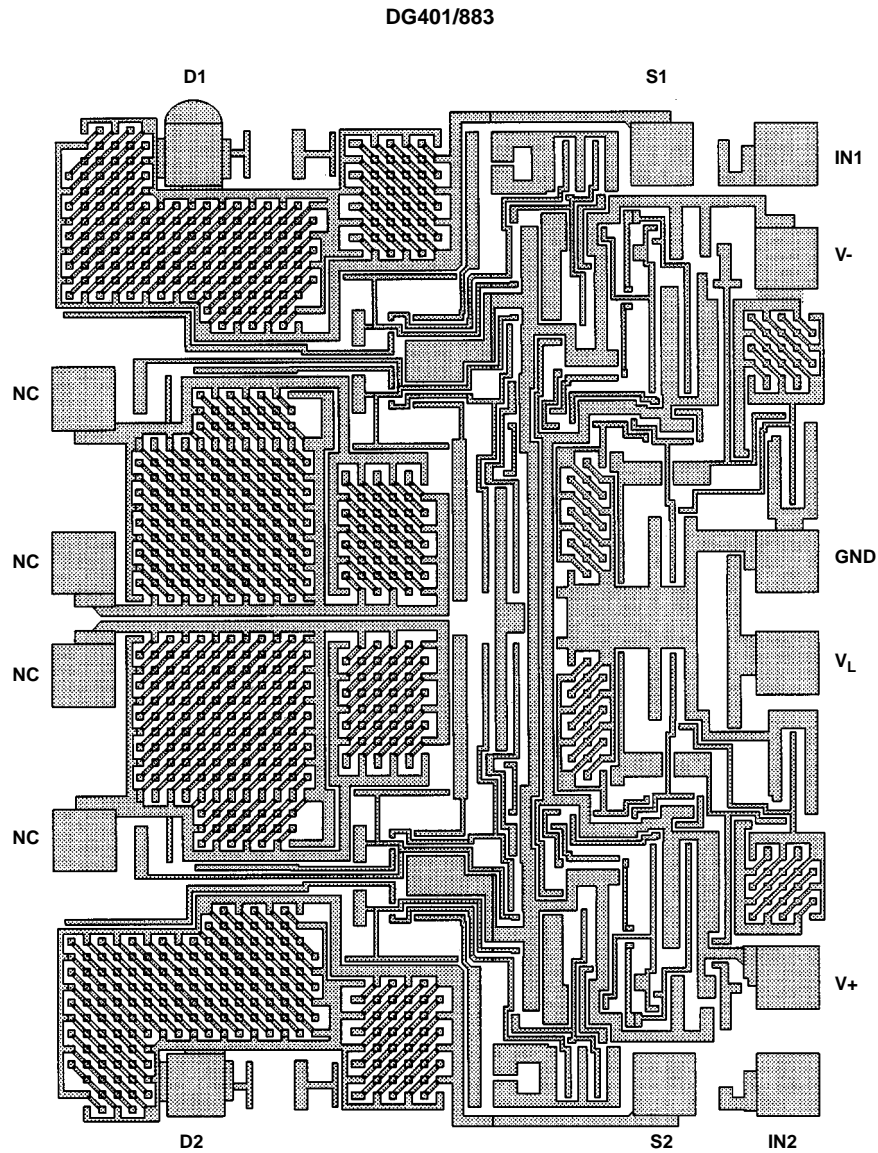
## *Die Characteristics*

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  Type: Si - Al
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**GLASSIVATION:**
  Type: Nitride
  Thickness: 8kÅ ± 1kÅ

**WORST CASE CURRENT DENSITY:**
  $1.5 \times 10^5 A/cm^2$

## *Metallization Mask Layout*

**DG403/883, DG405/883**

Spec Number **512046**
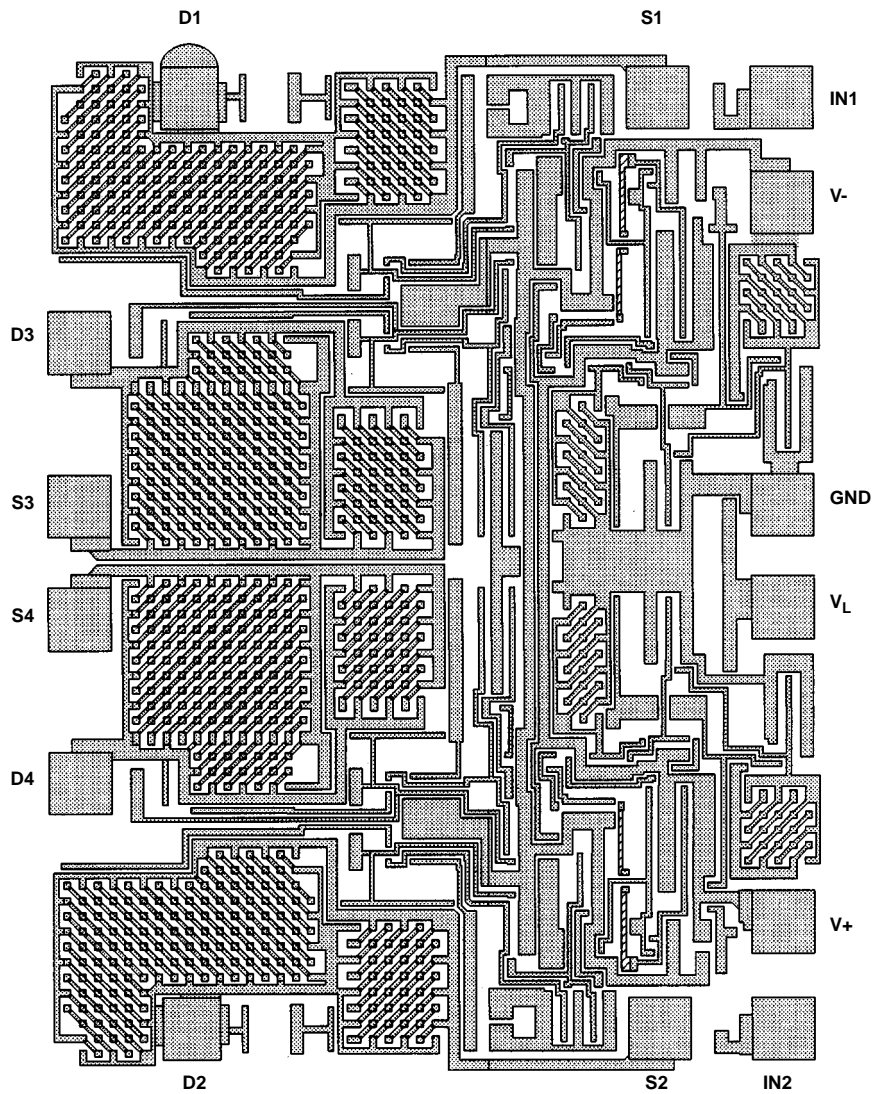
## Test Circuits
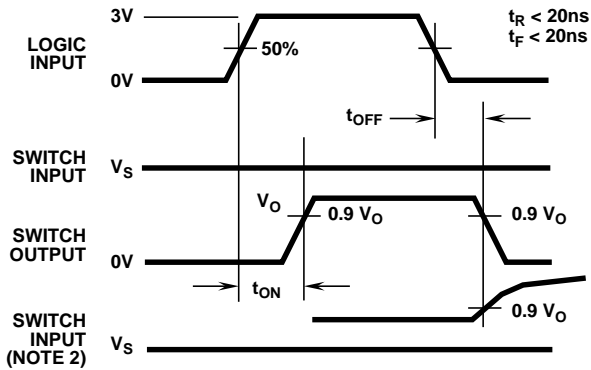


NOTES:

1. Logic input waveform is inverted for switches that have the opposite logic sense.

2. $V_S = 10V$ for $t_{ON}$, $V_S = -10V$ for $t_{OFF}$.

**FIGURE 1A.**

Repeat test for $IN_2$ and $S_2$
For load conditions, see Specifications. $C_L$ (includes fixture and stray capacitance)

$$V_O = V_S \frac{R_L}{R_L + r_{DS(ON)}}$$

**FIGURE 1B.**

**FIGURE 1.  SWITCHING TIME**
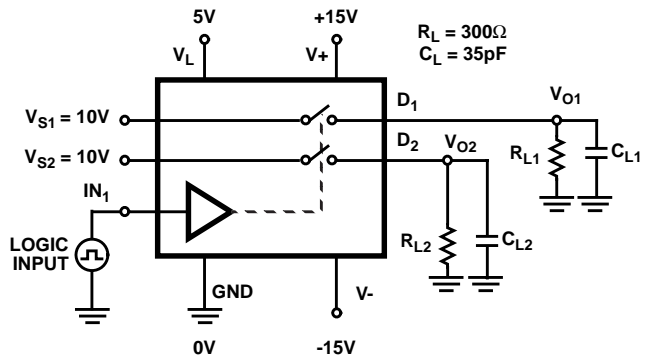


$C_L$ (includes fixture and stray capacitance)

**FIGURE 2A.**

**FIGURE 2B.**

**FIGURE 2.  BREAK-BEFORE-MAKE**

## Burn-In Circuit

**DG401/883, DG403/883, DG405/883**
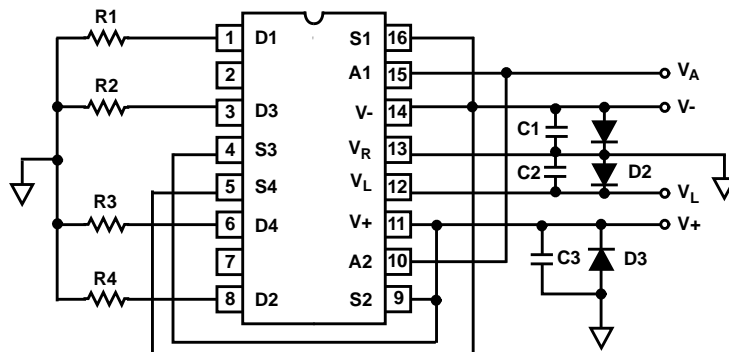
## Ceramic Dual-In-Line Frit Seal Packages (CerDIP)

**F16.3** MIL-STD-1835 GDIP1-T16 (D-2, CONFIGURATION A)
**16 LEAD CERAMIC DUAL-IN-LINE FRIT SEAL PACKAGE**
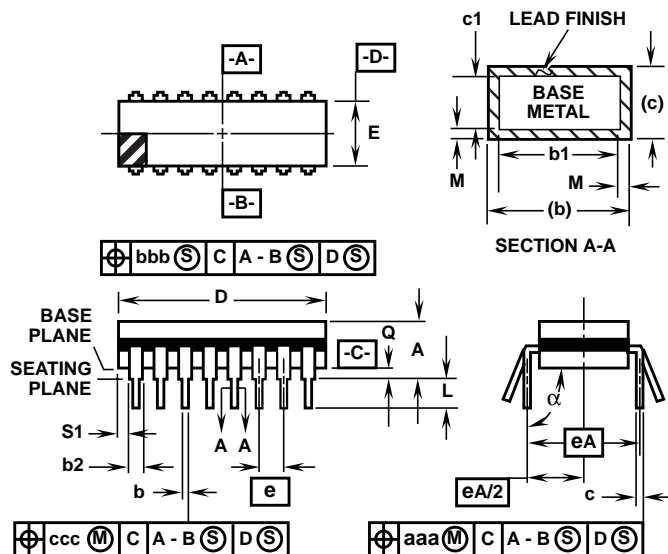
| SYMBOL | INCHES | | MILLIMETERS | | NOTES |
|---|---|---|---|---|---|
| | MIN | MAX | MIN | MAX | |
| A | - | 0.200 | - | 5.08 | - |
| b | 0.014 | 0.026 | 0.36 | 0.66 | 2 |
| b1 | 0.014 | 0.023 | 0.36 | 0.58 | 3 |
| b2 | 0.045 | 0.065 | 1.14 | 1.65 | - |
| b3 | 0.023 | 0.045 | 0.58 | 1.14 | 4 |
| c | 0.008 | 0.018 | 0.20 | 0.46 | 2 |
| c1 | 0.008 | 0.015 | 0.20 | 0.38 | 3 |
| D | - | 0.840 | - | 21.34 | 5 |
| E | 0.220 | 0.310 | 5.59 | 7.87 | 5 |
| e | 0.100 BSC | | 2.54 BSC | | - |
| eA | 0.300 BSC | | 7.62 BSC | | - |
| eA/2 | 0.150 BSC | | 3.81 BSC | | - |
| L | 0.125 | 0.200 | 3.18 | 5.08 | - |
| Q | 0.015 | 0.060 | 0.38 | 1.52 | 6 |
| S1 | 0.005 | - | 0.13 | - | 7 |
| $\alpha$ | $90^o$ | $105^o$ | $90^o$ | $105^o$ | - |
| aaa | - | 0.015 | - | 0.38 | - |
| bbb | - | 0.030 | - | 0.76 | - |
| ccc | - | 0.010 | - | 0.25 | - |
| M | - | 0.0015 | - | 0.038 | 2, 3 |
| N | 16 | | 16 | | 8 |

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NOTES:

1. Index area: A notch or a pin one identification mark shall be located adjacent to pin one and shall be located within the shaded area shown. The manufacturer's identification shall not be used as a pin one identification mark.

2. The maximum limits of lead dimensions b and c or M shall be measured at the centroid of the finished lead surfaces, when solder dip or tin plate lead finish is applied.

3. Dimensions b1 and c1 apply to lead base metal only. Dimension M applies to lead plating and finish thickness.

4. Corner leads (1, N, N/2, and N/2+1) may be configured with a partial lead paddle. For this configuration dimension b3 replaces dimension b2.

5. This dimension allows for off-center lid, meniscus, and glass overrun.

6. Dimension Q shall be measured from the seating plane to the base plane.

7. Measure dimension S1 at all four corners.

8. N is the maximum number of terminal positions.

9. Dimensioning and tolerancing per ANSI Y14.5M - 1982.

10. Controlling dimension: INCH.

11. Materials: Compliant to MIL-I-38535.

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Spec Number **512046**

# DESIGN INFORMATION

July 1999

## Monolithic CMOS Analog Switches

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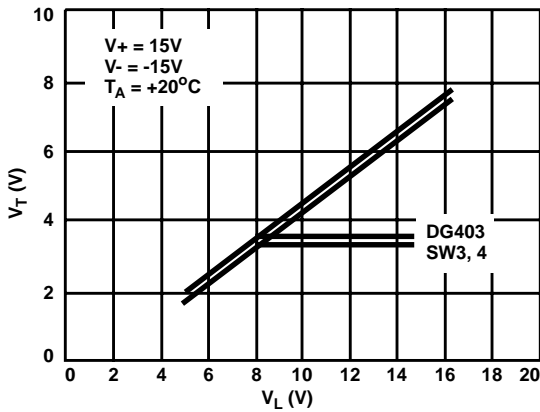
## *Typical Performance Curves*



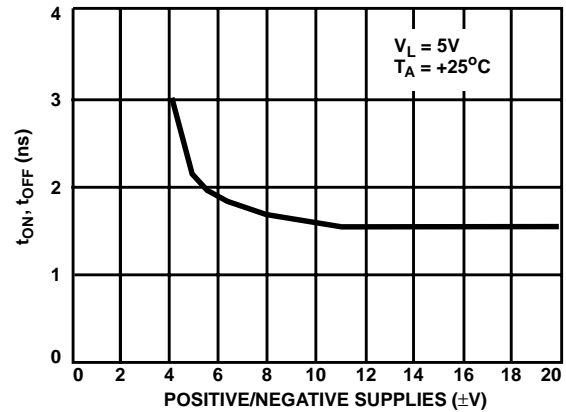FIGURE 3. INPUT SWITCHING THRESHOLD vs LOGIC SUPPLY VOLTAGE



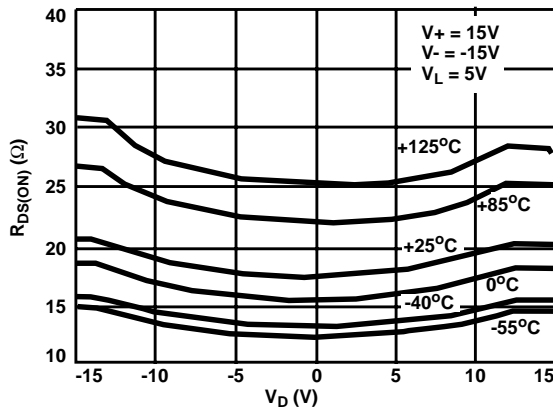FIGURE 4. INPUT SWITCHING THRESHOLD vs POWER SUPPLY VOLTAGE
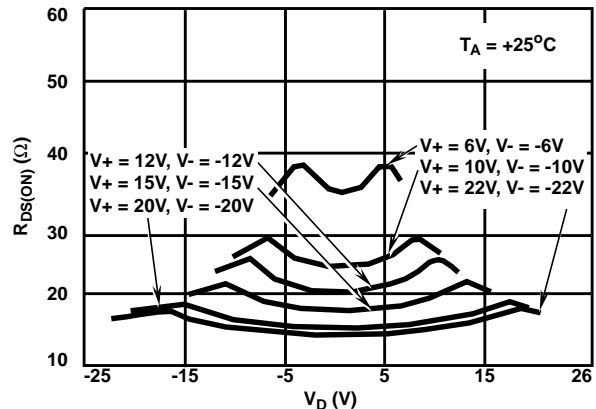


FIGURE 5. $R_{DS(ON)}$ vs $V_D$ AND TEMPERATURE



FIGURE 6. $R_{DS(ON)}$ vs $V_D$ AND POWER SUPPLY VOLTAGE
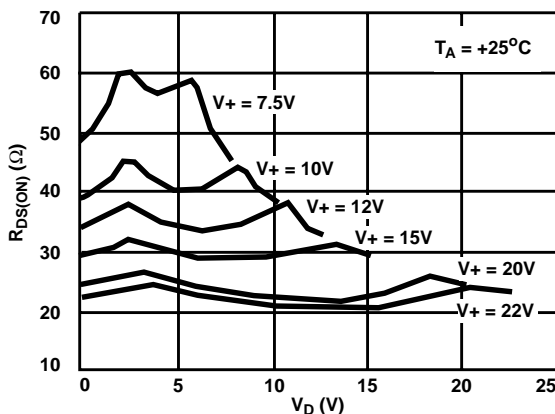


FIGURE 7. $R_{DS(ON)}$ vs $V_D$ AND POWER SUPPLY VOLTAGE, V- = -0V
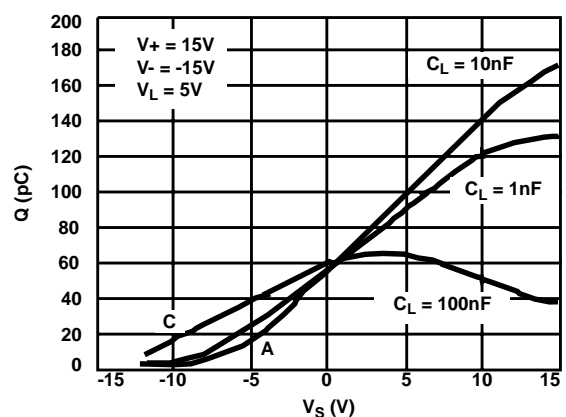


FIGURE 8. CHARGE INJECTION vs ANALOG VOLTAGE ($V_S$)

Spec Number **512046**

# DESIGN INFORMATION (Continued)

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## Typical Performance Curves (Continued)
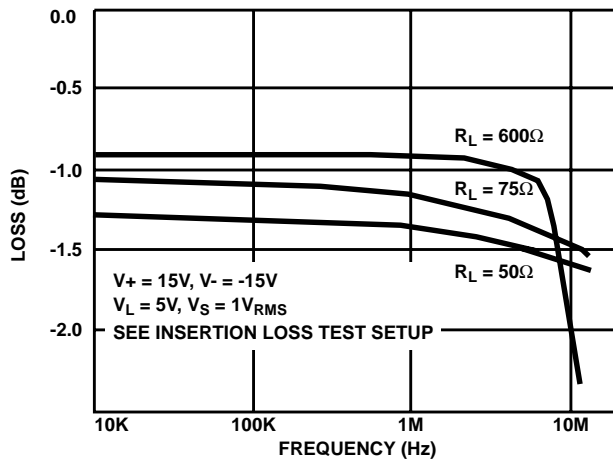
**FIGURE 9. INSERTION LOSS vs FREQUENCY**
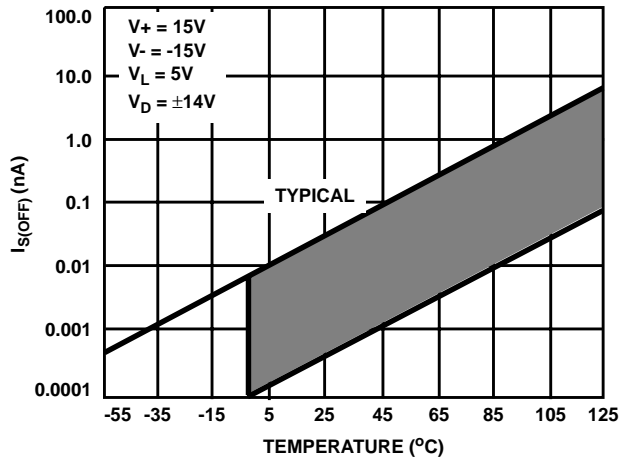
**FIGURE 10. $I_{S(OFF)}$ vs TEMPERATURE**
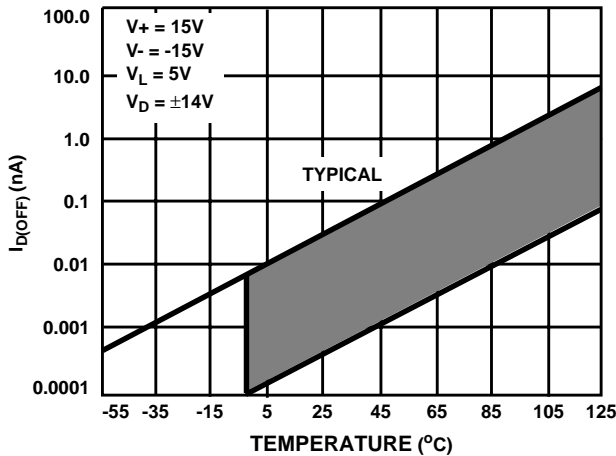
**FIGURE 11. $I_{D(OFF)}$ vs TEMPERATURE**
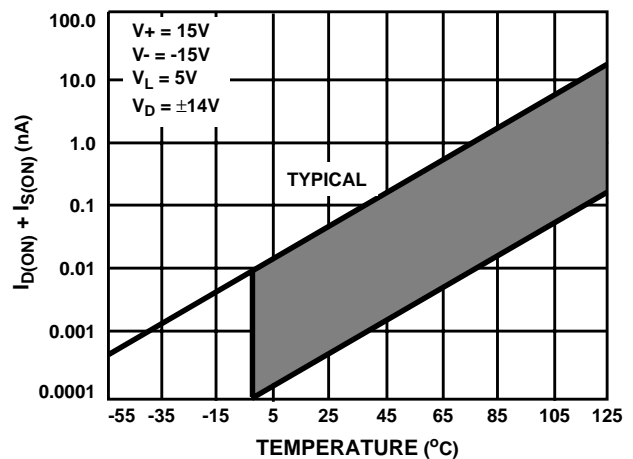
**FIGURE 12. $I_{D(ON)} + I_{S(ON)}$ vs TEMPERATURE**
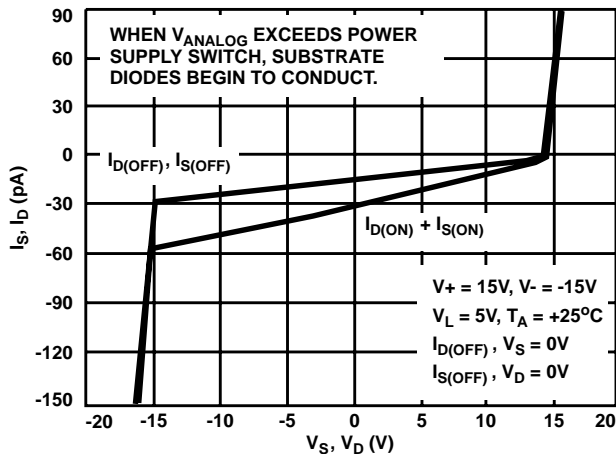
**FIGURE 13. LEAKAGE CURRENT vs ANALOG VOLTAGE**
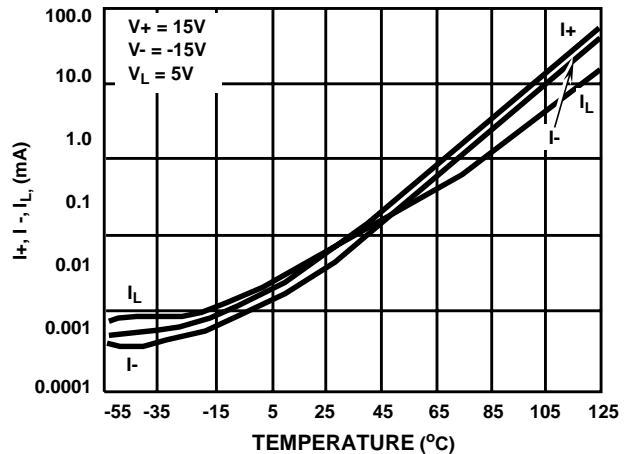
**FIGURE 14. SUPPLY CURRENT vs TEMPERATURE**

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## Typical Performance Curves (Continued)
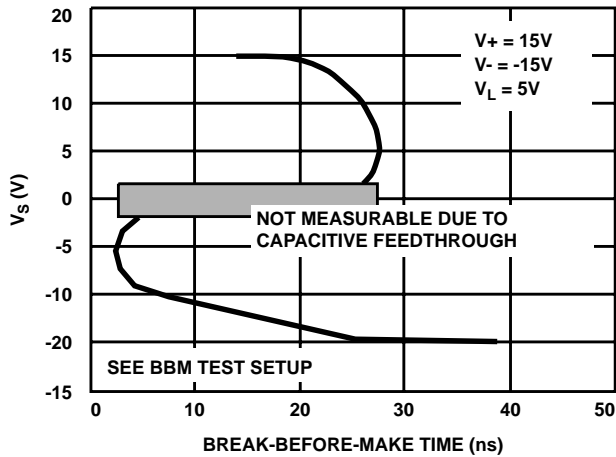


**FIGURE 15. BREAK-BEFORE-MAKE vs ANALOG VOLTAGE**
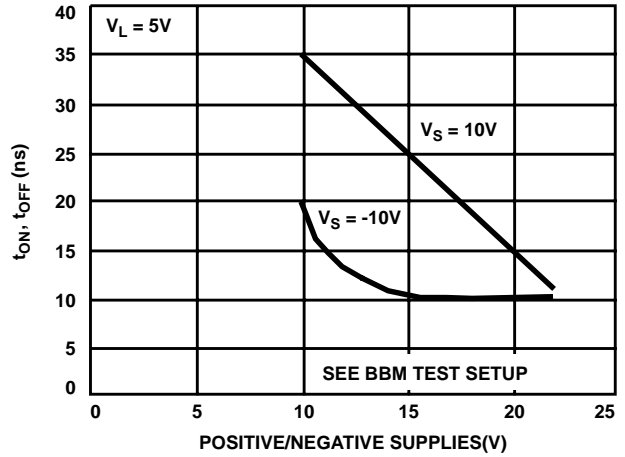


**FIGURE 16. BREAK-BEFORE-MAKE vs POWER SUPPLY VOLTAGE**
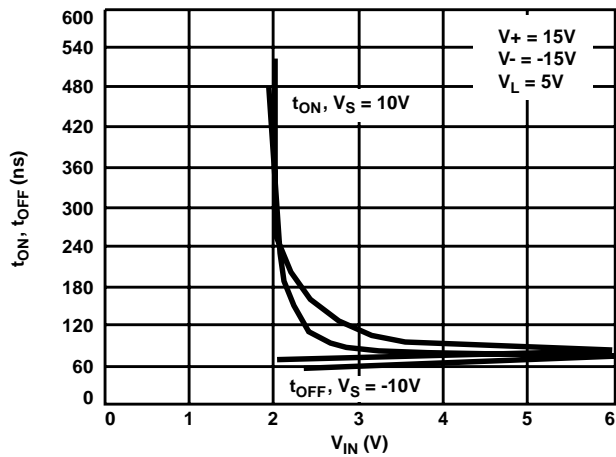


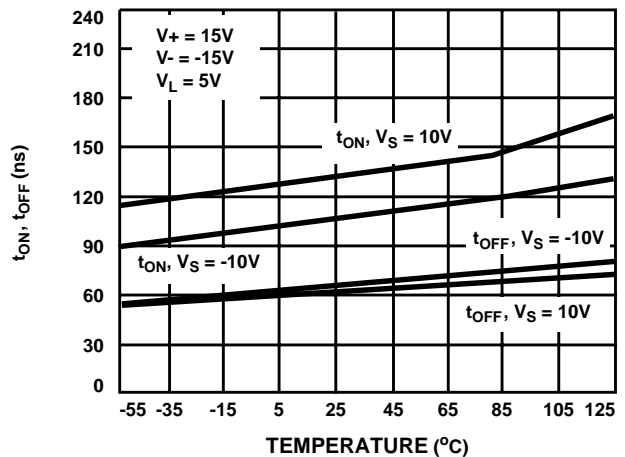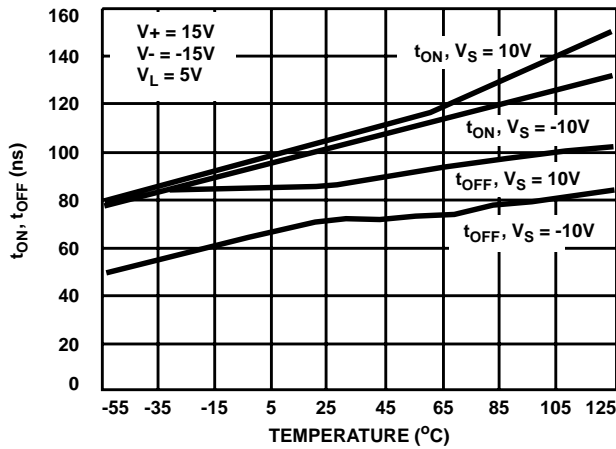**FIGURE 17. SWITCHING TIME vs INPUT LOGIC VOLTAGE ($V_{IN}$) REFER TO FIGURE 1 FOR TEST CONDITIONS.**



**FIGURE 18. SWITCHING TIME vs TEMPERATURE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
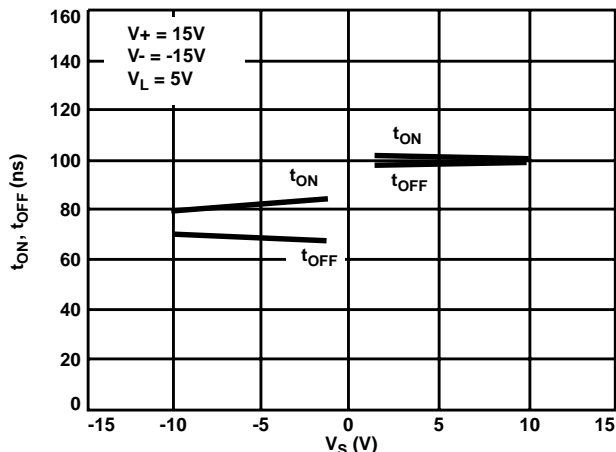


**FIGURE 19. SWITCHING TIME vs ANALOG VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
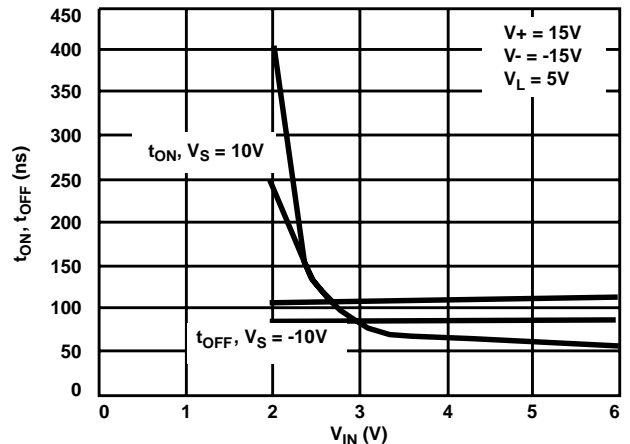


**FIGURE 20. SWITCHING TIME vs INPUT LOGIC VOLTAGE ($V_{IN}$), REFER TO FIGURE 1 FOR TEST CONDITIONS.**

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# DESIGN INFORMATION (Continued)

*The information contained in this section has been developed through characterization by Intersil Corporation and is for use as application and design information only. No guarantee is implied.*

## Typical Performance Curves (Continued)



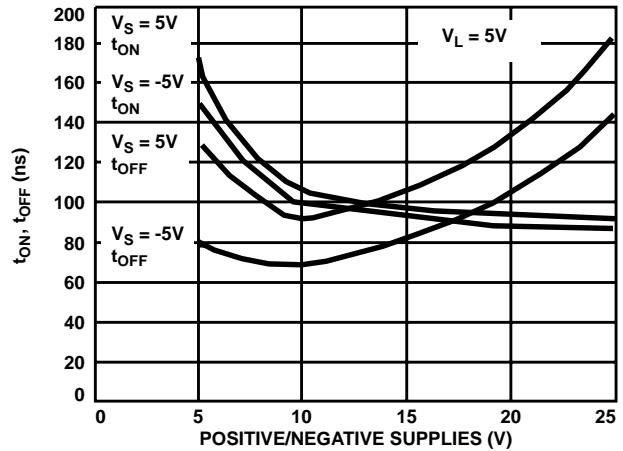**FIGURE 21. SWITCHING TIME vs TEMPERATURE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**



**FIGURE 22. SWITCHING TIME vs POWER SUPPLY VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
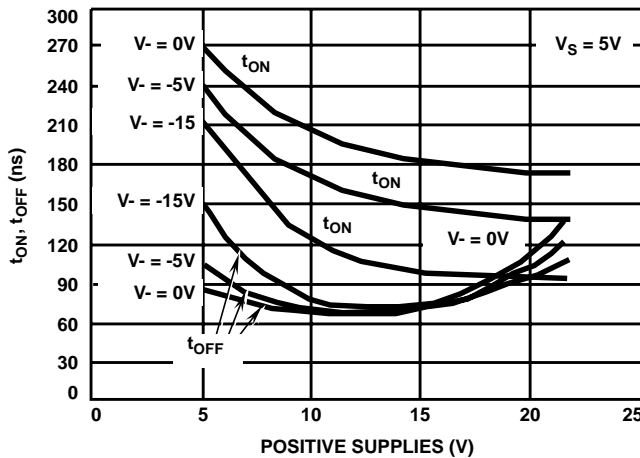


**FIGURE 23. SWITCHING TIME vs POSITIVE SUPPLY VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
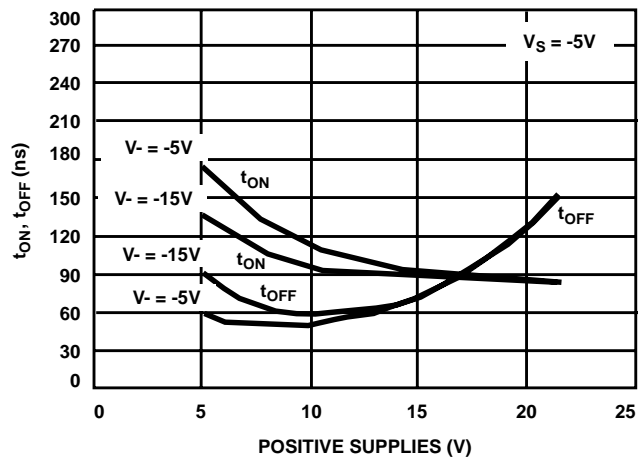


**FIGURE 24. SWITCHING TIME vs POSITIVE SUPPLY VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
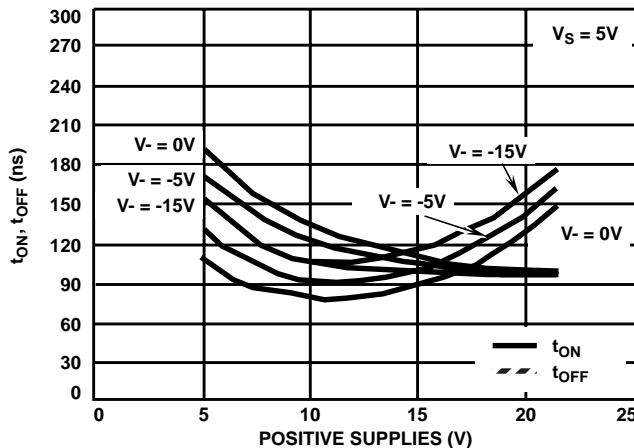


**FIGURE 25. SWITCHING TIME vs POSITIVE SUPPLY VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**
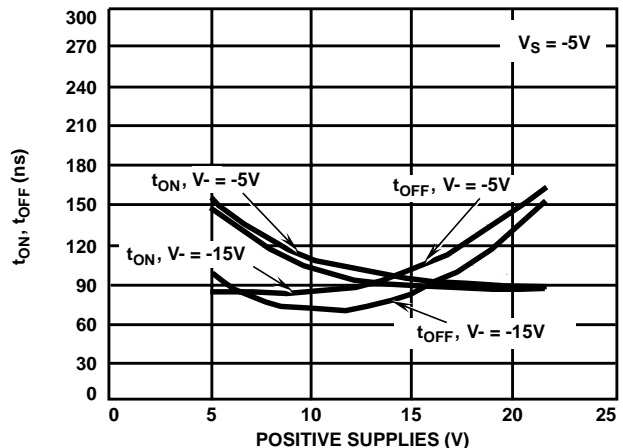


**FIGURE 26. SWITCHING TIME vs POSITIVE SUPPLY VOLTAGE, REFER TO FIGURE 1 FOR TEST CONDITIONS.**

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